



Product Summary

BV _{DSS}	Rds(on)	Ι _D Tc = +25°C
68V	8.0mΩ @ VGS = 10V	100A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

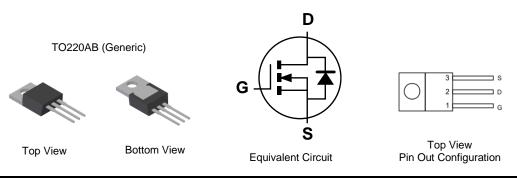
N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Input Capacitance
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: TO220AB
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (63)
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)



Ordering Information (Note 4)

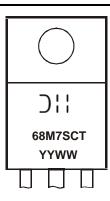
	Part Number	Case	Packaging				
	DMN68M7SCT	TO220AB (Generic)	50 Pieces/Tube				
Notes: 1 EU Directive 2002/95/EC (RoHS) 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied							

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



J = Manufacturer's Marking
68M7SCT = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 19 = 2019)
WW = Week (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	68	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 5) V_{GS} = 10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	ID	100 80	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 19		lом	400	A	
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			Ism	400	A
Maximum Continuous Body Diode Forward Current (Note 5)			ls	100	A
Avalanche Current (Note 6) L = 0.3mH			las	35	A
Avalanche Energy (Note 6) L = 0.3mH			E _{AS}	183	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) $T_{C} = + T_{C} = + T_{C}$	· · Pp	125 80	W
Thermal Resistance, Junction to Case (Note 5)	Rejc	1.0	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	68	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		_	1	μA	V _{DS} = 68V, V _{GS} = 0V	
Gate-Source Leakage	lgss	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)			•				
Gate Threshold Voltage	VGS(TH)	1.3	—	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	-	6.2	8.0	mΩ	Vgs = 10V, ID = 20A	
Diode Forward Voltage	Vsd	_	0.7	1.2	V	$V_{GS} = 0V, I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)			•				
Input Capacitance	Ciss	_	4260	—		V _{DS} = 30V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss		430	_	pF		
Reverse Transfer Capacitance	Crss	_	198	_			
Gate Resistance	Rg	_	1.75	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	QG	_	72.9	_		V _{DD} = 30V, I _D = 20A	
Total Gate Charge (V _{GS} = 4.5V)	QG	_	36.0	_	nC		
Gate-Source Charge	QGS	_	8.0	_	nc		
Gate-Drain Charge	Q _{GD}		15.3	_			
Turn-On Delay Time	td(on)	_	6.3	_		$V_{DD} = 30V, V_{GS} = 10V,$ $R_G = 1\Omega, I_D = 20A$	
Turn-On Rise Time	tR		18	_			
Turn-Off Delay Time	t _{D(OFF)}		36	_	ns		
Turn-Off Fall Time	tF	_	9.7	_]		
Reverse Recovery Time	trr	_	31.4	—	ns		
Reverse Recovery Charge	Qrr	_	30.1	—	nC	− I _F = 20A, di/dt = 100A/μs	

Notes: 5. Device mounted on infinite heatsink.

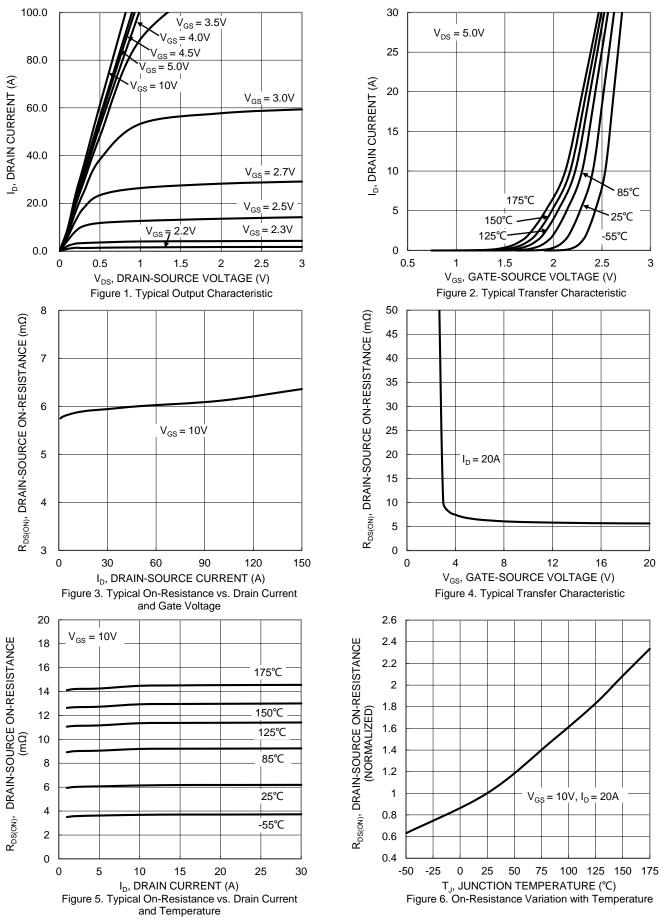
6. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

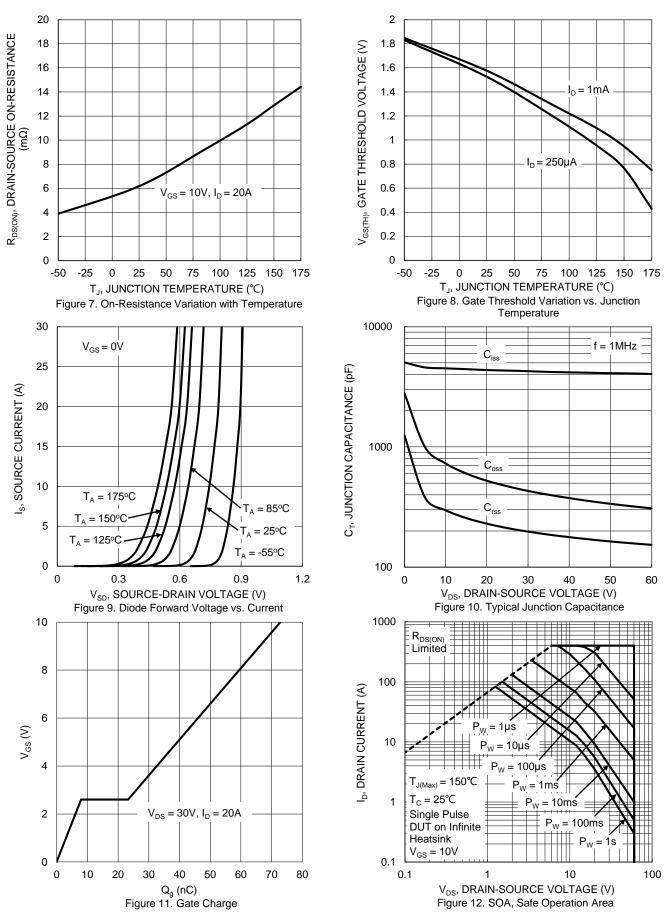


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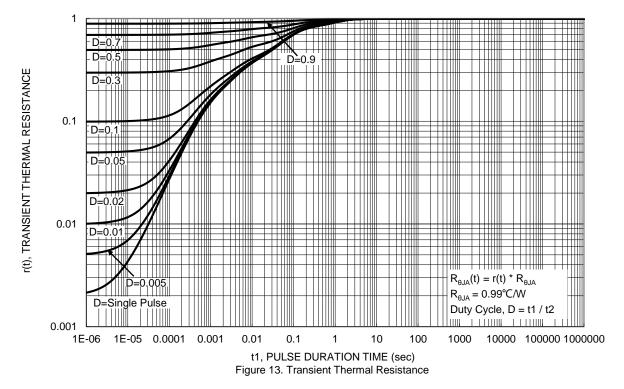
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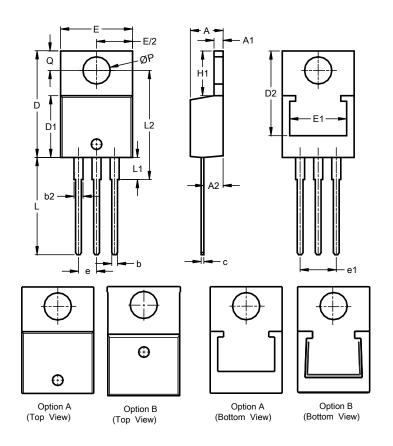




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO220AB (Generic)



TO220AB (Generic)					
Dim	Min	Max	Тур		
Α	3.56	4.82	-		
A1	0.51	1.39	1		
A2	2.04	2.92	-		
b	0.39	1.01	0.81		
b2	1.15	1.77	1.24		
С	0.356	0.61	-		
D	14.22	16.51	-		
D1	8.39	9.01	1		
D2	11.45	12.87	1		
е	-	-	2.54		
e1	-	-	5.08		
Е	9.66	10.66	1		
E1	6.86	8.89	1		
H1	5.85	6.85	1		
L	12.70	14.73	-		
L1	-	4.42	-		
L2	15.80	17.51	16.00		
Ρ	3.54	4.08	-		
Q	2.54	3.42	-		
All Dimensions in mm					



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